

FORM PTO-1449 (SUBSTITUTE)

U.S. DEPARTMENT OF COMMERCE
PATENT AND TRADEMARK OFFICE

Attorney Docket No.:

Z&PINFP08190

Applic. No.

09/904,360

Applicants

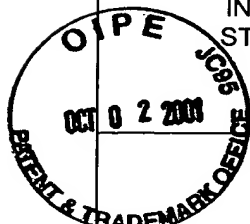
Giuseppe Curello et al.

Filing Date

July 12, 2001

Group Art Unit

2812

INFORMATION DISCLOSURE
STATEMENT BY APPLICANTS
(37 CFR 1.98(b))

U.S. PATENT DOCUMENTS

EXAMINER INITIALS		PATENT NO.	DATE	PATENTEE	CLASS	SUB CLASS	FILING DATE
IA	A	5,989,963	11/99	Luning et al.	—	—	—
IA	B	5,963,801	10/99	Aronowitz et al.	—	—	—
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		DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB CLASS	TRANSL. YES NO
	J						
	K						
	L						
	M						
	N						

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)

IA	O	Noda et al.: "0.1 μ m Delta-doped MOSFET using Post Low-energy Implanting Selective Epitaxy" 1994 Symposium on VLSI Technology Digest of Technical Papers, pages 19 - 20
IA	P	Priolo et al.: "Interface evolution and epitaxial realignment in polycrystal/single crystal Si structures" 1994 Elsevier Science B.V. 1994, Nuclear Instruments and Methods in Physics Research B85, pages 159 - 166

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DATE CONSIDERED

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicants.

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OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)

<u>IA</u>	O	Ran-Hong Yan et al.: "Scaling the Si MOSFET: From Bulk to SOI to Bulk", IEEE Transactions on Electron. Devices, Vol. 39, No. 7, July 1992, pages 1704 - 1711.
<u>IA</u>	P	Thompson et al.: "MOS Scaling: Transistor Challenges for the 21 st Century" Intel Technology Journal Q3'98, pages 1 - 19

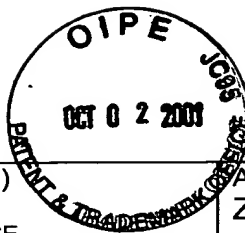
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OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)

1A	O	Curello et al.: "Beam-power heating effect on the synthesis of graded composition epitaxial Si _{1-x} Ge _x alloy layers" Elsevier Science B.V., 1997, Nuclear Instruments and Methods in Physics Research B 129, pages 377 - 386.
	P	

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U.S. PATENT DOCUMENTS

EXAMINER INITIALS		PATENT NO.	DATE	PATENTEE	CLASS	SUB CLASS	FILING DATE
IA	A	5,843,829	12/01/98	Kuramae et al.	_____	_____	
IA	B	6,048,781	04/11/00	Turner et al.	_____	_____	
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		DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB CLASS	TRANSL. YES NO
IA	J	0 889 502 A2	01/07/99	Europe	_____	_____	X
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